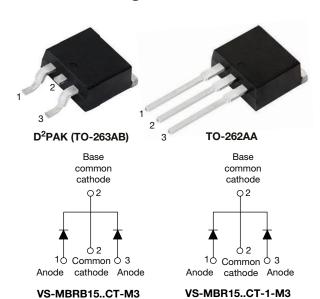
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 7.5 A



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 7.5 A					
V_{R}	35 V, 45 V					
V _F at I _F	0.57 V					
I _{RM} max.	15 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	7 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- 150 °C T_{.I} operation
- Center tap TO-220 package
- Low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBR(B)15... center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	15	Α			
V _{RRM}		35/45	V			
I _{FSM}	t _p = 5 μs sine	690	Α			
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V			
T _J		-65 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBRB1535CT-M3 VS-MBR1535CT-1-M3	VS-MBRB1545CT-M3 VS-MBR1545CT-1-M3	UNITS		
Maximum DC reverse voltage	V_{R}	35	45	V		
Maximum working peak reverse voltage	V_{RWM}	33	45	V		



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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS				
Maximum average per leg		T _ 121 °C roto	ad V	7.5				
forward current per device	I _{F(AV)}	$I_C = 131$ C, rate	T _C = 131 °C, rated V _R		= 131 °C, rated V _R			
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	690 A				
non-repetitive surge	I _{FSM}	Surge applied at single phase, 60	rated load conditions halfwave, Hz	150				
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 3.5$ mH		7	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T _A maximum V _A = 1.5 x V _B typical		2	Α			

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		15 A	T _J = 25 °C	0.84			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	7.5 A	T _{.I} = 125 °C	0.57	V		
		15 A	1J = 125 C	0.72			
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA		
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	15			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	nge 100 kHz to 1 MHz), 25 °C	400	pF		
Typical series inductance	L _S	Measured from top of terr	minal to mounting plane	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,~duty~cycle < 2~\%$

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperat	ture range	TJ		-65 to +150	°C		
Maximum storage temperat	ure range	T _{Stg}		-65 to +175)		
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	3.0			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W		
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation	60			
Ai				2	g		
Approximate weight				0.07	oz.		
Mounting torque minimum maximum				6 (5)	kgf · cm		
				12 (10)	(lbf · in)		
Marking device			Case style D ² PAK (TO-263AB)	MBRB1	545CT		
			Case style TO-262AA	MBR15	45CT-1		

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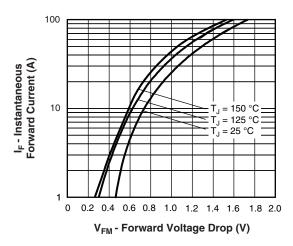


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

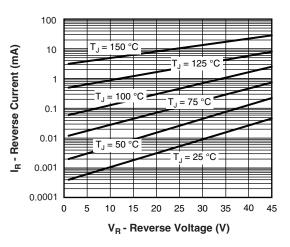


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

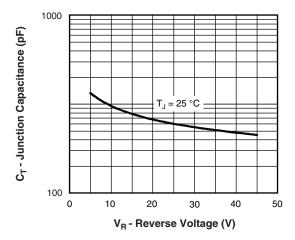


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

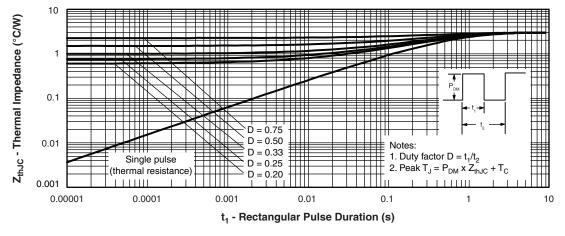


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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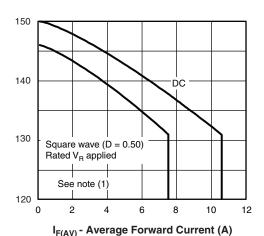


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

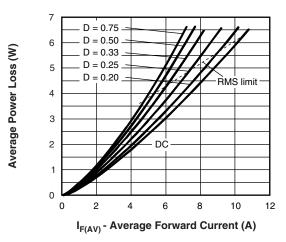


Fig. 6 - Forward Power Loss Characteristics

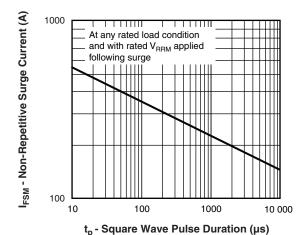


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

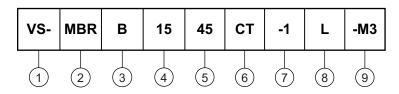
Allowable Case Temperature (°C)

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Essential part number

• B = D^2PAK (TO-263AB) None = -1

• None = TO-262AA

Current rating (15 = 15 A)

35 = 35 VVoltage ratings -45 = 45 V

CT = essential part number

• None = D^2PAK = B • -1 = TO-262AA None

8 • None = tube

• L = tape and reel (left oriented - for D²PAK (TO-263AB) only)

• R = tape and reel (right oriented - for D²PAK (TO-263AB) only)

9 -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-MBRB1535CTL-M3	800	13" diameter plastic tape and reel					
VS-MBRB1535CT-M3	50	Antistatic plastic tubes					
VS-MBRB1535CTR-M3	800	13" diameter plastic tape and reel					
VS-MBRB1545CTL-M3	800	13" diameter plastic tape and reel					
VS-MBRB1545CT-M3	50	Antistatic plastic tubes					
VS-MBRB1545CTR-M3	800	13" diameter plastic tape and reel					
VS-MBR1535CT-1-M3	50	Antistatic plastic tubes					
VS-MBR1545CT-1-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				
SPICE model		www.vishay.com/doc?95294				



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D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	CVMPOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	J1E3	STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

Revision: 13-Jul-17 Document Number: 96164

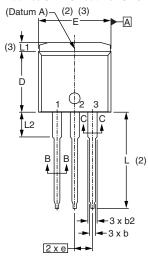


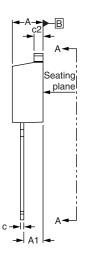
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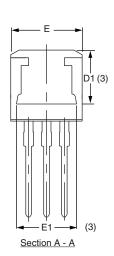
TO-262AA

DIMENSIONS in millimeters and inches

Modified JEDEC® outline TO-262







⊕ 0.010 **M** A**M** B

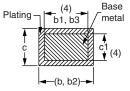
Lead assignments



Diodes 1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	IETERS	INC	INCHES			
	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
Е	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	BSC	0.10	0 BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.56	3.71	0.140	0.146			

Notes

(4) Dimension b1 and c1 apply to base metal only

Controlling dimension: inches

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)



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